

Abstracts

Balanced Dual Gate GaAs FET Frequency Doublers

R. Stancliff. "Balanced Dual Gate GaAs FET Frequency Doublers." 1981 MTT-S International Microwave Symposium Digest 81.1 (1981 [MWSYM]): 143-145.

A new technique for broadband microwave power generation is presented: The balanced dual gate MESFET frequency doubler. Design and results for 18-26.5 GHz and 4-23 GHz doublers are presented.

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